

# Industrial SD Card

## 3TE4

**Customer:** \_\_\_\_\_

**Customer**

**Part**

**Number:** \_\_\_\_\_

**Innodisk**

**Part**

**Number:** \_\_\_\_\_

**Innodisk**

**Model Name:** \_\_\_\_\_

**Date:** \_\_\_\_\_

| <b>Innodisk Approver</b> | <b>Customer Approver</b> |
|--------------------------|--------------------------|
|                          |                          |

**Total Solution For  
Industrial Flash Storage**

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## REVISION HISTORY

| Revision        | Description                           | Date       |
|-----------------|---------------------------------------|------------|
| Preliminary 0.1 | First release                         | May, 2021  |
| V1.0            | Official release                      | Nov.,2021  |
| V.1.1           | Revised NAND Flash Memory information | Jan., 2022 |
| V1.2            | Operating temperature correction      | Jul., 2022 |
| V1.3            | Add 112-L 3D TLC                      | Oct., 2022 |

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# 1. Product Overview

## 1.1 Introduction of Innodisk Industrial SD 3TE4

Innodisk 3TE4 is an industrial-grade SD card solution with an integrated industrial controller, which is designed for embedded applications. With enhanced flash technologies and a powerful configurable BCH ECC engine, SD 3TE4 can achieve high-speed data transfer rates.

Innodisk industrial SD 3TE4 provides a wide range of capacities from 32GB to 256GB with TLC NAND Flash, and is fully compliant with SD3.0 and SD2.0 specifications.

Innodisk industrial SD 3TE4 are specifically designed for industrial PC and embedded applications for high performance. With its low power consumption and the above-mentioned features, Innodisk industrial SD 3TE4 can be applied for industrial automation, SBC (single-board computer), medical equipment, infotainment, and mobile applications.

## 1.2 Product View and Models

Innodisk Industrial SD 3TE4 is available from 32GB up to 256GB capacities within TLC Flash IC.

[SD 3TE4 32GB](#)

[SD 3TE4 64GB](#)

[SD 3TE4 128GB](#)

[SD 3TE4 256GB](#)



**Figure 1: Innodisk Industrial SD 3TE4**

## 1.3 SD 3.0 Interface

Innodisk Industrial SD 3TE4 support SD 3.0 interface, and backward compliant to SD 2.0 interface.

## 2. Product Specifications

### 2.1 Capacity and Device Parameters

Innodisk Industrial SD card device parameters are shown in Table 1.

**Table 1: Device parameters**

| Capacity | LBA       |
|----------|-----------|
| 32GB     | 61079552  |
| 64GB     | 122159104 |
| 128GB    | 244318208 |
| 256GB    | 488636416 |

### 2.2 Performance

Burst Transfer Rate: UHS-I (up to 104 MB/s in SD 3.0 SDR104)

**Table 2: Performance- 64/96 Layers 3D TLC\***

| Capacity                             | 32GB<br>(64-L) | 64GB<br>(96-L) | 128GB<br>(96-L) | 256GB<br>(96-L) |
|--------------------------------------|----------------|----------------|-----------------|-----------------|
| <b>Speed Class</b>                   | 10             | 10             | 10              | 10              |
| <b>UHS Class</b>                     | U3             | U3             | U3              | U3              |
| <b>Sequential Read (max.)</b>        | 90 MB/s        | 90 MB/s        | 90 MB/s         | 90 MB/s         |
| <b>Sequential Write (max.)</b>       | 35 MB/s        | 30 MB/s        | 65 MB/s         | 80 MB/s         |
| <b>4KB Random**<br/>Read (QD32)</b>  | 1,900 IOPS     | 1,800 IOPS     | 1,800 IOPS      | 1,800 IOPS      |
| <b>4KB Random**<br/>Write (QD32)</b> | 590 IOPS       | 700 IOPS       | 750 IOPS        | 750 IOPS        |

Note: \* Performance results are measured in Room Temperature with Out-of-Box devices and may vary depending on overall system setup.

Note: \*\*Performance results are base on CrystalDiskMark 6.0.2 with file size 1000MB

**Table 3: Performance- 112 Layers 3D TLC\***

| Capacity                          | 64GB       | 128GB      | 256GB      |
|-----------------------------------|------------|------------|------------|
| <b>Speed Class</b>                | 10         | 10         | 10         |
| <b>UHS Class</b>                  | U3         | U3         | U3         |
| <b>Sequential Read (max.)</b>     | 90 MB/s    | 90 MB/s    | 90 MB/s    |
| <b>Sequential Write (max.)</b>    | 40 MB/s    | 80 MB/s    | 80 MB/s    |
| <b>4KB Random** Read (Q32T1)</b>  | 2,000 IOPS | 2,000 IOPS | 2,000 IOPS |
| <b>4KB Random** Write (Q32T1)</b> | 800 IOPS   | 800 IOPS   | 800 IOPS   |

Note: \* Performance results are measured in Room Temperature with Out-of-Box devices and may vary depending on overall system setup.

Note: \*\*Performance results are base on CrystalDiskMark 6.0.2 with file size 1000MB

**Table 4: Memory Card Speed Specification**

| Minimum Sequential Write Speed | Speed Class           | UHS Speed Class      |
|--------------------------------|-----------------------|----------------------|
| <b>30 MB/s</b>                 |                       | <b>Class 30 (U3)</b> |
| <b>10 MB/s</b>                 | <b>Class 10 (C10)</b> | <b>Class 10 (U1)</b> |
| <b>6 MB/s</b>                  | <b>Class 6 (C6)</b>   |                      |
| <b>4 MB/s</b>                  | <b>Class 4 (C4)</b>   |                      |
| <b>2 MB/s</b>                  | <b>Class 2 (C2)</b>   |                      |

## 2.3 Electrical Specifications

### 2.3.1 Power Requirement

**Table 5: Innodisk Industrial SD card Power Requirement**

| Item          | Symbol          | Rating    | Unit |
|---------------|-----------------|-----------|------|
| Input voltage | V <sub>IN</sub> | 2.7V~3.6V | V    |

## 2.3.2 Power Consumption

**Table 6: Power Consumption**

| Mode        | Power Consumption (W) |
|-------------|-----------------------|
| Read (rms)  | 0.5                   |
| Write (rms) | 0.7                   |
| Peak (max)  | 1.3                   |
| Idle (rms)  | 0.0009                |

## 2.4 Environmental Specifications

### 2.4.1 Temperature Ranges

**Table 7: Temperature range for Industrial SD card**

| Temperature | Range                            |
|-------------|----------------------------------|
| Operating   | Standard Grade: -25°C to +85°C   |
|             | Industrial Grade: -40°C to +85°C |
| Storage     | -40°C to +85°C                   |

### 2.4.2 Humidity

Relative Humidity: 10-95%, non-condensing

### 2.4.3 Shock and Vibration

**Table 8: Shock/Vibration Testing for Industrial SD card**

| Reliability      | Test Conditions                 | Reference Standards |
|------------------|---------------------------------|---------------------|
| Vibration        | 7 Hz to 2K Hz, 20G, 3 axes      | IEC 68-2-6          |
| Mechanical Shock | Duration: 0.5ms, 1500 G, 3 axes | IEC 68-2-27         |

### 2.4.4 Mean Time between Failures (MTBF)

Table 7 summarizes the MTBF prediction results for various Industrial SD card configurations. The analysis was performed using a RAM Commander™ failure rate prediction.

- **Failure Rate:** The total number of failures within an item population, divided by the total number of life units expended by that population, during a particular measurement interval under stated condition.
- **Mean Time between Failures (MTBF):** A basic measure of reliability for repairable items: The mean number of life units during which all parts of the item perform within their specified limits, during a particular measurement interval under stated conditions.

**Table 9: Industrial SD card MTBF**

| Product                     | Condition                 | MTBF (Hours) |
|-----------------------------|---------------------------|--------------|
| Innodisk Industrial SD 3TE4 | Telcordia SR-332 GB, 25°C | >3,000,000   |

## 2.5 CE and FCC Compatibility

Industrial SD card conforms to CE and FCC requirements.

## 2.6 RoHS Compliance

Industrial SD card is fully compliant with RoHS directive.

## 2.7 Reliability

| Parameter   | Value                      |
|---|----------------------------|
| Read Cycles   | Unlimited Read Cycles      |
| Flash endurance   | 3,000 P/E cycles           |
| Wear-Leveling Algorithm   | Support                    |
| Bad Blocks Management   | Support                    |
| Error Correct Code  | Support                    |
| <b>TBW* (Total Bytes Written)</b> Unit:TB                         |                            |
| <b>Capacity</b>   | <b>Sequential workload</b> |
| 32GB  | 85.22                      |
| 64GB  | 170.45                     |
| 128GB   | 340.90                     |
| 256GB   | 681.81                     |
| *Note:<br>Sequential: Mainly sequential write, tested by Vdbench. |                            |

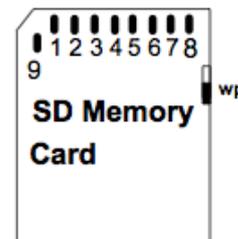
## 2.8 Transfer Mode

Industrial SD 3TE4 support following transfer mode:

SD 3.0 / SD 2.0

## 2.9 Pin Assignment

Innodisk Industrial SD 3TE4 compliant with standard SD SPEC., please refer to Table 8 for pin assignment.

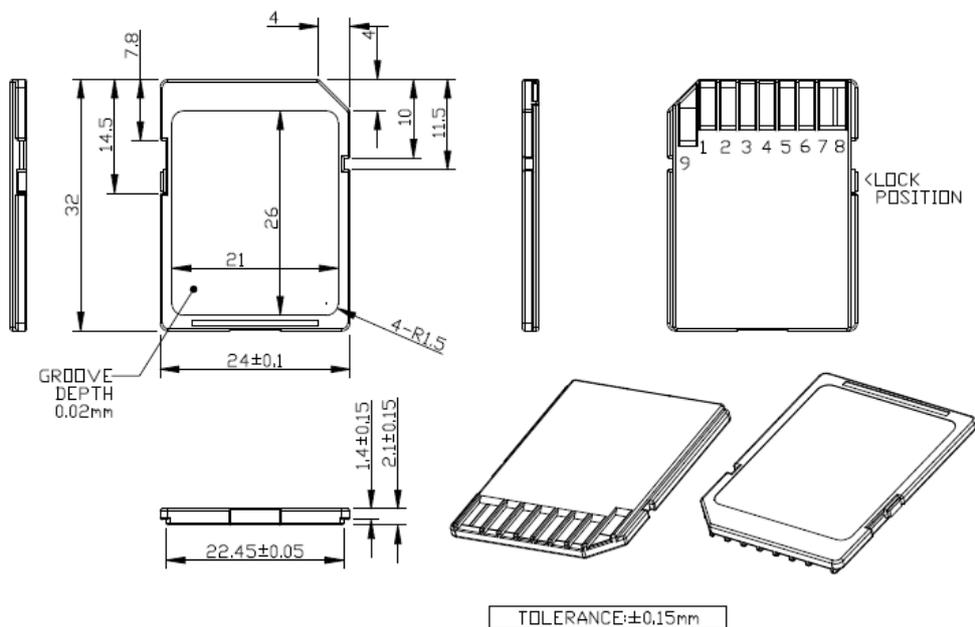


**Table 10. SD card Pin Assignment**

| Pin # | SD Mode              |                     |                               | SPI Mode        |                   |                         |
|-------|----------------------|---------------------|-------------------------------|-----------------|-------------------|-------------------------|
|       | Name                 | Type <sup>1</sup>   | Description                   | Name            | Type <sup>1</sup> | Description             |
| 1     | CD/DAT3 <sup>2</sup> | I/O/PP <sup>3</sup> | Card Detect/Data Line [Bit 3] | CS              | I <sup>3</sup>    | Chip Select (Neg. True) |
| 2     | CMD                  | I/O/PP              | Command/Response              | DI              | I                 | Data In                 |
| 3     | V <sub>SS1</sub>     | S                   | Supply voltage ground         | V <sub>SS</sub> | S                 | Supply voltage ground   |
| 4     | V <sub>DD</sub>      | S                   | Supply voltage                | V <sub>DD</sub> | S                 | Supply voltage          |

|   |                   |        |                       |                  |      |                       |
|---|-------------------|--------|-----------------------|------------------|------|-----------------------|
| 5 | CLK               | I      | Clock                 | SCLK             | I    | Clock                 |
| 6 | V <sub>SS2</sub>  | S      | Supply voltage ground | V <sub>SS2</sub> | S    | Supply voltage ground |
| 7 | DAT0              | I/O/PP | Data Line [Bit 0]     | DO               | O/PP | Data Out              |
| 8 | DAT1 <sup>4</sup> | I/O/PP | Data Line [Bit 1]     | RSV              |      |                       |
| 9 | DAT2 <sup>5</sup> | I/O/PP | Data Line [Bit 2]     | RSV              |      |                       |

## 2.10 Mechanical Dimensions



## 2.11 Assembly Weight

An Innodisk Industrial SD card 3.0 within MLC flash ICs, 8GB's weight is 2 grams approx.

## 2.12 Seek Time

Innodisk Industrial SD card is not a magnetic rotating design. There is no seek or rotational latency required.

## 2.13 Hot Plug

The SD card support hot plug function and can be removed or plugged-in during operation.

## 2.14 NAND Flash Memory

Innodisk Industrial SD 3TE4 uses 3D TLC NAND flash memory, which is non-volatility, high reliability and high speed memory storage.

## 2.15 Card Identification Register

The Card Identification (CID) register is 128 bits wide. It contains the card identification information used during the card identification phase. Every individual flash card shall have a unique identification number. The structure of the CID register is defined in the following table.

**Table 11 Innodisk Industrial SD Card CID Table**

| CID bit   | Width | Name                  | Field |
|-----------|-------|-----------------------|-------|
| [127:120] | 8     | Manufacturer ID       | MID   |
| [119:104] | 16    | OEM/Application ID    | OID   |
| [103:64]  | 40    | Product Name          | PNM   |
| [63:56]   | 8     | Product Revision      | PRV   |
| [55:24]   | 32    | Product Serial Number | PSN   |
| [23:20]   | 4     | Reserved              | ---   |
| [19:8]    | 12    | Manufacturing Date    | MDT   |
| [7:1]     | 7     | CRC7 check sum        | CRC   |
| [0]       | 1     | Not used, always '1'  | ---   |

## 2.16 SMART List

**Table 12.SMART List**

| Offset | Byte Count | Attribute Name                 | Description  |
|--------|------------|--------------------------------|--|
| 0x000  | 16         | Reserved for Unique ID/Setting | Reserved for Unique ID/Setting   |
| 0x010  | 1          | Bus Width                      | 00h: 1 bit width<br>10h: 4 bit width   |
| 0x011  | 1          | Secured Mode                   | 00h: Not in the secured mode<br>01h: In secured mode   |
| 0x012  | 1          | Speed Class                    | 00h: Class 0<br>01h: Class 2<br>02h: Class 4<br>03h: Class 6<br>04h: Class 10                  |
| 0x013  | 1          | UHS Speed Grade                | 00h: Less than 10MB/sec<br>01h: 10MB/sec and above<br>02h: Reserved<br>03h: 30MB/sec and above |
| 0x014  | 4          | Protected Area Size            | Protected Area Size (Bytes)  |

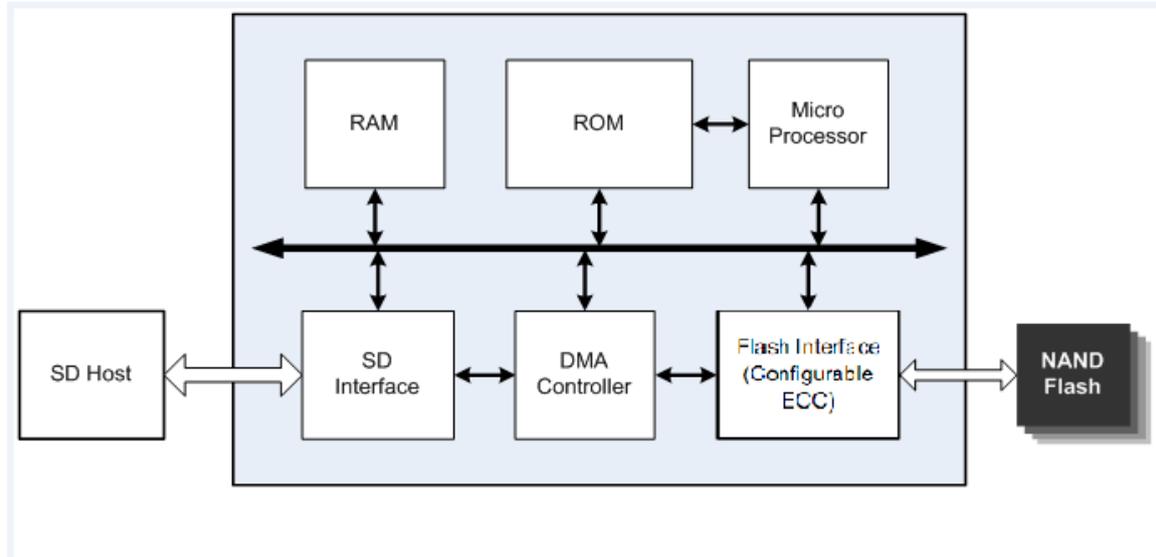
|       |   |  |  |
|-------|---|--|--|
| 0x018 | 2 | Original Bad Block Count               | Original Bad Block Count   |
| 0x01A | 1 | RTBB Count                             | Run-time Bad Block Count   |
| 0x01B | 1 | Total SLC Spare Count                  | Total SLC Spare Block Count  |
| 0x01C | 4 | Reserved                               | Reserved   |
| 0x020 | 4 | Min. Erase Count (Data Block)          | Minimum Erase Count (Data Block)(TLC Block)  |
| 0x024 | 4 | Max. Erase Count (Data Block)          | Maximum Erase Count (Data Block)(TLC Block)  |
| 0x028 | 4 | Total Erase Count (Data Block)         | Total Erase Count (Data Block)(TLC Block)  |
| 0x02C | 4 | Avg. Erase Count (Data Block)          | Average Erase Count (Data Block)(TLC Block)  |
| 0x030 | 4 | Min. Erase Count (System Table Block)  | Minimum Erase Count (System Table Block)(SLC Block)  |
| 0x034 | 4 | Max. Erase Count (System Table Block)  | Maximum Erase Count (System Table Block)(SLC Block)  |
| 0x038 | 4 | Total Erase Count (System Table Block) | Total Erase Count (System Table Block)(SLC Block)  |
| 0x03C | 4 | Avg. Erase Count (System Table Block)  | Average Erase Count (System Table Block)(SLC Block)  |
| 0x040 | 4 | Raw Card Capacity                      | Raw Card Capacity (MB)   |
| 0x044 | 2 | NAND P/E Cycle                         | NAND P/E Cycle (unit : 100 times )(TLC Block)  |
| 0x046 | 1 | Card Life (%)                          | Remaining Card Life (%) = (NAND P/E Cycle - Avg. Erase Count (MLC or TLC))/NAND P/E Cycle (TLC Block)        |
| 0x047 | 1 | Current SD Card Speed Mode             | 0x00: Default speed<br>0x01: High speed mode<br><br>0x10: SDR12<br>0x11: SDR25<br>0x12: SDR50<br>0x14: DDR50 |

|       |    |                                |  |
|-------|----|--------------------------------|--|
|       |    |                                | 0x18: SDR104   |
| 0x048 | 4  | Total Write CRC Count          | Total Write CRC Count  |
| 0x04C | 4  | Power On/Off Count             | Power On/Off Count   |
| 0x050 | 6  | NAND Flash ID                  | NAND Flash ID (6 Bytes max.)(Only read flash ID for CE0)   |
| 0x056 | 1  | MID                            | MID  |
| 0x057 | 1  | Group Number                   | Group Number, ex. x4 with 4-way, group number=1, x4 with 2-way, group number=2                                   |
| 0x058 | 8  | SMI SD Controller P/N          | SMI SD Controller P/N (e.g. SM2706)  |
| 0x060 | 2  | Read Claim Count (TLC Block)   | Read Claim Count (Data on TLC Block) Host reads data on TLC Block and needs soft-decode case                     |
| 0x062 | 2  | Read Claim Count (SLC Block)   | Read Claim Count (Data on SLC Block) Host reads data on SLC Block and needs soft-decode case                     |
| 0x064 | 2  | Firmware Block Refresh Counter | ISP Block refresh counter  |
| 0x066 | 2  | Reserved                       | Reserved Area  |
| 0x068 | 4  | TLC Read Count Threshold       | TLC Read Count Threshold ( unit : 100 times )  |
| 0x06C | 4  | SLC Read Count Threshold       | SLC Read Count Threshold ( unit : 100 times )  |
| 0x070 | 16 | First TLC for each group       | First TLC Block for each group   |
| 0x080 | 6  | SD Firmware Version            | SD Firmware Version (e.g. R0321x)  |
| 0x086 | 2  | Reserved                       | Reserved Area  |
| 0x088 | 4  | Data Refresh Count (TLC Block) | Data Refresh Count (TLC Block) Host reads data on TLC Block and read count is over TLC read count threshold case |
| 0x08C | 4  | Data Refresh Count (SLC Block) | Data Refresh Count (SLC Block) Host reads data on SLC Block and read count is over SLC read count threshold case |
| 0x090 | 16 | CID Register                   | CID Register   |

## 3. Theory of Operation

### 3.1 Overview

Figure 2 shows the operation of Innodisk Industrial SD 3TE4 from the system level, including the major hardware blocks.



**Figure 2: Innodisk Industrial SD 3TE4 Block Diagram**

Innodisk Industrial SD 3TE4 integrates a SD 3.0 controller and NAND flash memories. Communication with the host occurs through the host interface, using the standard SD interface.

### 3.2 SD 3.0 Controller

Innodisk Industrial SD 3TE4 is designed with a SD 3.0 controller, which has single channel for flash interface.

### 3.3 Error Detection and Correction

Highly sophisticated Error Correction Code algorithms are implemented. The ECC unit consists of the Parity Unit (parity-byte generation) and the Syndrome Unit (syndrome-byte computation). This unit implements an algorithm that can correct up to 43 bits per 1024 bytes in an ECC block. Code-byte generation during write operations, as well as error detection during read operation, is implemented on the fly without any speed penalties.

### 3.4 Wear-Leveling

Flash memory can be erased within a limited number of times. This number is called the **erase cycle limit** or **write endurance limit** and is defined by the flash array vendor. The erase cycle limit applies to each individual erase block in the flash device.

Innodisk Industrial SD 3TE4 uses a global wear-leveling algorithm to ensure that consecutive writes of a specific sector are not written physically to the same page/block in the flash. This spreads flash media usage evenly across all pages, thereby extending flash lifetime.

### 3.5 Bad Blocks Management

Bad Blocks are blocks that contain one or more invalid bits whose reliability are not guaranteed. The Bad Blocks may be presented while the product is shipped, or may develop during the life time of the SD card. When the Bad Blocks is detected, it will be flagged, and not be used anymore. The SD card implement Bad Blocks management, Bad Blocks replacement, Error Correct Code to avoid data error occurred. The functions will be enabled automatically to transfer data from Bad Blocks to spare blocks, and correct error bit.

### 3.6 Garbage Collection

Garbage collection is used to maintain data consistency and perform continual data cleansing on SD card. It runs as a background process, freeing up valuable controller resources while sorting good data into available blocks, and deleting bad blocks. It also significantly reduces write operations to the drive, thereby increasing the SD's speed and lifespan.

### 3.7 Power cycling

Innodisk's SD/MSDs provide the complete data protection mechanism during every abnormal power shutdown situation. Such as: power failure at programming data, updating system tables, erasing blocks, etc. The mechanism can maintain the data correctness and increase the reliability of the data stored in the NAND Flash memory.

## 4. Installation Requirements

### 4.1 Industrial SD card Pin Directions

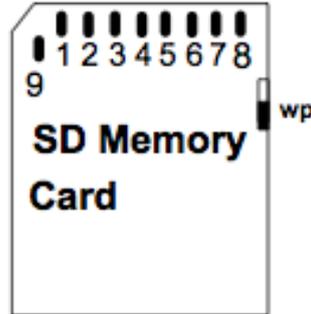


Figure 3: Signal Segment and Power Segment

### 4.2 Device Drive

No additional device drives are required.

## 5. Part Number Rule

| CODE  | 1    | 2                  | 3 | 4 | 5 | 6 | 7        | 8 | 9 | 10       | 11 | 12  | 13         | 14              | 15               | 16  | 17    | 18 | 19              | 20 |
|---|------|--------------------|---|---|---|---|----------|---|---|----------|----|---|------------|-----------------|------------------|-----|-------|----|-----------------|----|
|   | D    | E                  | S | D | C | - | A        | 2 | 8 | S        | 0  | 6   | G          | E               | 1                | S   | L     | -  | X               | X  |
| Description   | Disk | Industrial SD card |   |   |   |   | Capacity |   |   | Category |    |   | Flash Mode | Operation Temp. | Internal Control | CH. | Flash | -  | Customized Code |    |
| <b>Definition</b>   |      |                    |   |   |   |   |          |   |   |          |    |   |            |                 |                  |     |       |    |                 |    |
| <b>Code 1<sup>st</sup> (Disk)</b>                         |      |                    |   |   |   |   |          |   |   |          |    | <b>Code 13<sup>th</sup> (Flash Mode)</b>                      |            |                 |                  |     |       |    |                 |    |
| D : Disk  |      |                    |   |   |   |   |          |   |   |          |    | E: 64 Layers 3D TLC   |            |                 |                  |     |       |    |                 |    |
|   |      |                    |   |   |   |   |          |   |   |          |    | G: 96 Layers 3D TLC   |            |                 |                  |     |       |    |                 |    |
|   |      |                    |   |   |   |   |          |   |   |          |    | K: 112 Layers 3D TLC  |            |                 |                  |     |       |    |                 |    |
| <b>Code 2<sup>nd</sup> ~ 5<sup>th</sup> (Form Factor)</b> |      |                    |   |   |   |   |          |   |   |          |    | <b>Code 14<sup>th</sup> (Operation Temperature)</b>           |            |                 |                  |     |       |    |                 |    |
| ESDC: Industrial SD                                       |      |                    |   |   |   |   |          |   |   |          |    | E: Extend Grade (-25°C~ +85°C)                                |            |                 |                  |     |       |    |                 |    |
|   |      |                    |   |   |   |   |          |   |   |          |    | W: Industrial Grade (-40°C~ +85°C)                            |            |                 |                  |     |       |    |                 |    |
| <b>Code 7<sup>th</sup> ~9<sup>th</sup> (Capacity)</b>     |      |                    |   |   |   |   |          |   |   |          |    | <b>Code 15<sup>th</sup> (Internal control)</b>                |            |                 |                  |     |       |    |                 |    |
| 32G: 32GB   |      |                    |   |   |   |   |          |   |   |          |    | 1: Product version  |            |                 |                  |     |       |    |                 |    |
| 64G: 64GB   |      |                    |   |   |   |   |          |   |   |          |    | <b>Code 16<sup>th</sup> (Channel of data transfer)</b>        |            |                 |                  |     |       |    |                 |    |
| A28G: 128GB   |      |                    |   |   |   |   |          |   |   |          |    | S: Single Channel   |            |                 |                  |     |       |    |                 |    |
| B56G: 256GB   |      |                    |   |   |   |   |          |   |   |          |    | <b>Code 17<sup>th</sup> (Flash Type)</b>                      |            |                 |                  |     |       |    |                 |    |
|   |      |                    |   |   |   |   |          |   |   |          |    | L: Innodisk 3D TLC  |            |                 |                  |     |       |    |                 |    |
| <b>Code 10<sup>th</sup> ~12<sup>th</sup> (Controller)</b> |      |                    |   |   |   |   |          |   |   |          |    | <b>Code 19<sup>th</sup>~20<sup>th</sup> (Customized Code)</b> |            |                 |                  |     |       |    |                 |    |
| S06: SM2706   |      |                    |   |   |   |   |          |   |   |          |    |   |            |                 |                  |     |       |    |                 |    |